

Time: 3 Hours

Code No.: 20ECC35

Max Marks: 60

(4)

4

## CHAITANYA BHARATHI INSTITUTE OF TECHNOLOGY (Autonomous)

## B.E. III Sem (Main) Examination February/March 2022

## **Basic Electronics**

(Common to CSE, CSE-AI&ML, CSE-IoT&CS)

*Note:* Answer ALL questions from Part-A & Part -B (Internal Choice) at one place in the same order Part - A  $(5Q \times 3M = 15 \text{ Marks})$ M CO BT 1 Differentiate diffusion and drift currents in PN-Junction semiconductor 1 2 (3) 2 Illustrate h-parameter equivalent circuit for CE-Configuration. (3) 2 2 List out the advantages of Negative Feedback Amplifier. 3 3 1 (3) 4 What are the ideal characteristics of an OPAMP? (3) 4 1 5 5 Define the principle of photo diode. (3) 1 Part – B  $(5Q \times 9M = 45 \text{ Marks})$ M CO BT 6 (a) Illustrate the energy levels and band gap of Intrinsic and Extrinsic (5) 1 2 Semiconductor. (b) Analyze the characteristics of P-N Junction diode. (4) 1 4 (OR) 7 (a) Determine the Full wave Bridge Rectifier's Ripple factor and 1 4 efficiency. (b) Analyze the role of filters in rectifiers. 1 4 (4) 8 (a) Explain how Zener diode acts as a voltage regulator. (5) 2 4 (b) Interpret the Avalanche and Zener Breakdown mechanisms. (4) 2 4 (OR)9 (a) Derive the Common Source JFET parameters. (5) 2 2 (b) Distinguish BJT and FET in various parameters. 2 4 (4) (a) Derive the expression for frequency of Colpitts oscillator with 10 (5) 3 4 necessary illustrations. (b) Distinguish positive and negative feedback amplifiers. 4 (4) 3 (OR) 11 (a) Evaluate the frequency of RC-phase shift oscillator with necessary 3 2 (5) illustrations. (b) What are the necessary conditions to get the sustained oscillations? 3 1 (4) (a) Determine the efficiency of Class B amplifier. 12 (5) 4 3 (b) Compare Class A, Class AB and Class C power amplifiers. 4

(OR)



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